

■ Features

• High Output Power: P5dB=48.0dBm (Typ.)

• High Linear Gain: GL=13.0dB (Typ.)

High Power Added Efficiency: PAE=40% (Typ.)

Broad Band: 7.7 to 8.5GHzHermetically Sealed Package



The SGK7785-60C is a high power GaN-HEMT that is internally matched for standard communication bands to provide optimum power and gain in a 50ohm system.



ABSOLUTE MAXIMUM RATING (Case Temperature $T_c=25 \text{ deg.C}$)

Item	Symbol	Rating		
Drain-Source Voltage	V _{DS}	26	V	
Gate-Source Voltage	V _{GS}	-10	V	
Total Power Dissipation	P _T	150	W	
Storage Temperature	T _{stg}	-55 to +125	deg.C	
Channel Temperature	T _{ch}	+250	deg.C	
Case Temperature	T _c	-40 to +125	deg.C	

RECOMMENDED OPERATING CONDITION

Item	Symbol	Condition	Limit	Unit			
Drain-Source Voltage	V _{DS}		<=24	V			
Forward Gate Current	I_{GF}	Rg=51ohm	<=8.8	mA			
Reverse Gate Current	I_{GR}	Rg=51ohm	>=-4.6	mA			
Channel Temperature	T _{ch}		<+193	deq.C			

ELECTRICAL CHARACTERISTICS (Case Temperature T_c=25 deg.C)

Thomas	Cumbal	Condition	Limit			1124	
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	
Saturated Drain Current	I_{DSS}	V _{DS} =10V, V _{GS} =0V	-	16.6	-	Α	
Trans Conductance	G _m	V _{DS} =24V, I _{DS} =1.92A	-	4.4	-	S	
Pinch-off Voltage	V _P	V _{DS} =24V, I _{DS} =1.92mA	-2.5	-4.0	-5.5	V	
Output Power at 5dB G.C.P.	P _{5dB}		47.0	48.0	-	dBm	
Linear Gain at Pin=27dBm	GL	V _{DS} =24V(typ.)	9.5	13.0	-	dB	
Drain Current at 5dB G.C.P.	I_{DSR}	I _{DS(DC)} =2.6A(typ.) f=7.7 to 8.5 GHz	-	6.4	7.0	Α	
Power Added Efficiency at 3dB G.C.P.	PAE	Vgs-constant	-	40	-	%	
Gain Flatness	ΔG	vgs constant	-	-	1.6	dB	
3rd Order Inter Modulation Distortion	IM ₃	f=7.7GHz, 8.5GHz Δf=10MHz, 2-tone Test Pout=32.0dBm (S.C.L.)	-38.0	-42.0	-	dBc	
Thermal Resistance	R _{th}	Channel to Case (Tc=25deg.C, Pdiss=62.4W)	-	1.3	1.5	deg.C/W	
Channel Temperature Rise	ΔT_{ch}	(V _{DS} x I _{DSR} - Pout + Pin) x R _{th}	-	110	150	deg.C	

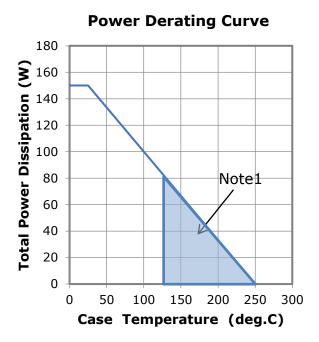
G.C.P.: Gain Compression Point, S.C.L.: Single Carrier Level

CASE STYLE	IBK	
RoHS Compliance	YES	
ESD *1	Class 2	2000V to < 4000V

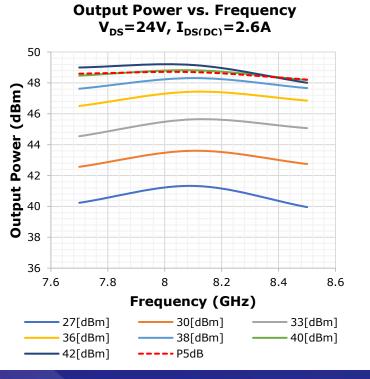
Note: *1 Based on ANSI/ESDA/JEDEC JS-001-2012(C=100pF, R=1.5kohm)



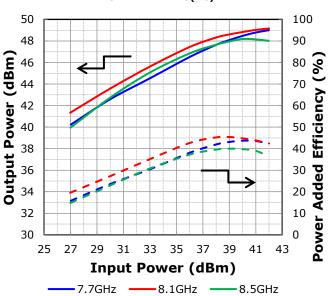
RF Characteristics



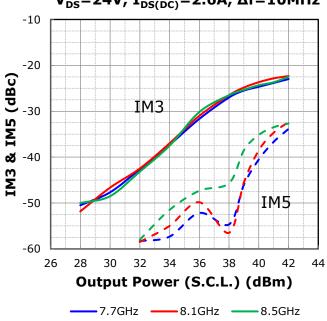
Note 1: Shaded area exceeds Maximum Case Operating Temperature (See Page1)



Input Power vs. Output Power and Power Added Efficiency V_{DS} =24V, $I_{DS(DC)}$ =2.6A

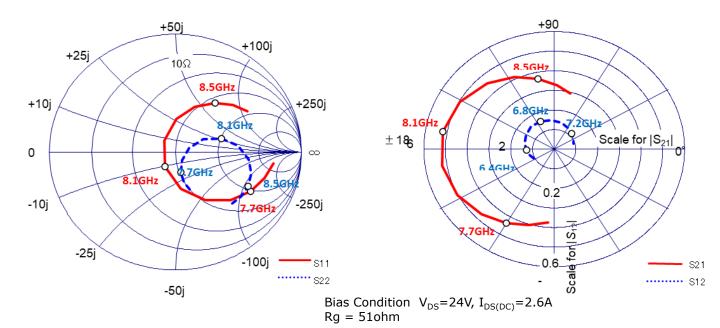


IMD vs. Output Power (S.C.L.) $V_{DS}=24V$, $I_{DS(DC)}=2.6A$, $\Delta f=10MHz$





• S-Parameter

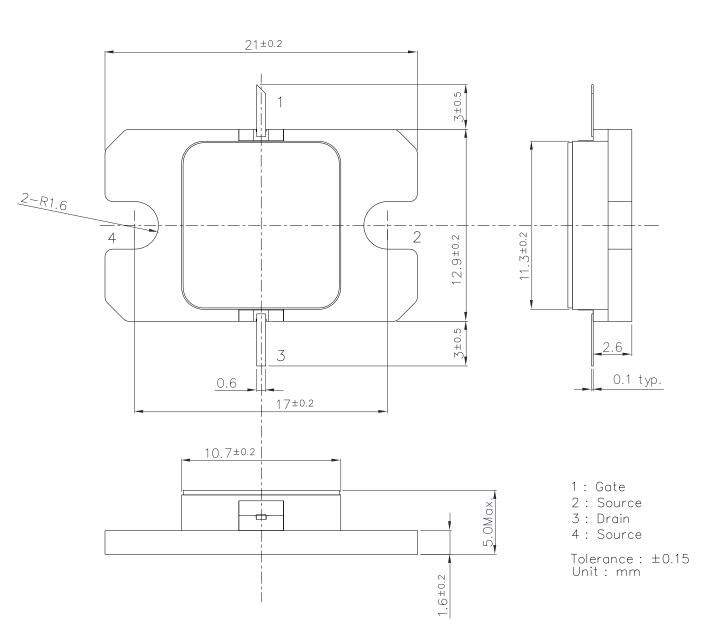


Erog	S11	511		S21		S12		S22	
Freq.	mag phase		mag phase		mag phase		mag phase		
7.5GHz	0.781	-7.0	3.737	-94.4	0.053	-153.3	0.337	-70.1	
7.6GHz	0.742	-17.3	4.045	-106.5	0.058	-165.0	0.265	-75.0	
7.7GHz	0.685	-29.0	4.357	-120.2	0.063	-177.9	0.178	-75.8	
7.8GHz	0.597	-42.9	4.717	-135.3	0.069	167.7	0.088	-54.0	
7.9GHz	0.474	-59.7	5.035	-152.2	0.074	151.0	0.114	16.5	
8GHz	0.314	-81.9	5.225	-170.5	0.078	133.0	0.246	25.8	
8.1GHz	0.145	-123.5	5.209	170.1	0.078	113.7	0.386	17.6	
8.2GHz	0.133	131.3	4.979	150.7	0.075	94.7	0.501	6.0	
8.3GHz	0.281	88.2	4.559	132.6	0.069	76.5	0.583	-6.0	
8.4GHz	0.416	67.8	4.110	116.4	0.063	60.1	0.627	-17.1	
8.5GHz	0.521	52.9	3.666	101.5	0.056	44.6	0.644	-26.9	
8.6GHz	0.606	41.2	3.271	87.8	0.051	30.7	0.644	-35.9	
8.7GHz	0.669	31.4	2.941	75.4	0.046	18.0	0.628	-43.9	



• Package Outline

Case Style : IBK





For Safety, Observe the Following Procedures Environmental Management

- Do not put this product into the mouth.
- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Respect all applicable laws of the country when discarding this product.
 This product must be disposed in accordance with methods specified by applicable hazardous waste procedures.

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